

## WS3A002065E

## Silicon Carbide Schottky Diode

V <sub>RRM</sub>	=	650	V
I <sub>F</sub> ( T <sub>C</sub> ≤135°C)	=	4	Α
Q <sub>C</sub>	=	5.4	nC

#### **Features**

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

## **Applications**

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

## **Package**





TO-252



Part Number	Package	Marking
WS3A002065E	TO-252	WS3A002065E

## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	V	T <sub>C</sub> = 25°C	
$V_{RSM}$	Surge Peak Reverse Voltage	650	V	T <sub>C</sub> = 25°C	
V <sub>R</sub>	DC Blocking Voltage	650	V	T <sub>C</sub> = 25°C	
I <sub>F</sub>	Forward Current	8 4 2	А	$T_C \le 25^{\circ}C$ $T_C \le 135^{\circ}C$ $T_C \le 161^{\circ}C$	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	20	Α	$T_C = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	39	W	T <sub>C</sub> = 25°C	Fig.3
T <sub>C</sub>	Maximum Case Temperature	161	°C		
$T_J, T_{STG}$	Operating Junction and Storage Temperature	-55 to 175	°C		



#### **Electrical Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
V <sub>F</sub>	Forward Voltage	1.4	1.65	V	I <sub>F</sub> = 2A, T <sub>J</sub> = 25°C	Fig.1	
		1.7	2.3 V	I <sub>F</sub> = 2A, T <sub>J</sub> = 175°C	1 19.1		
	Reverse Current	1	10		$V_R = 650V, T_J = 25^{\circ}C$	Fig.2	
I <sub>R</sub>	Reverse Current	5	100	μA	$V_R = 650V$ , $T_J = 175^{\circ}C$	Fig.2	
		125			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$		
С	Total Capacitance	12	/	pF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5	
		10			$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$		
Qc	Total Capacitive Charge	- A			$V_R = 650V, I_F = 2A$	Fig.4	
		Q <sub>C</sub> Total Capacitive Charge 5.4	5.4	/	nC	di/dt = 200A/µs, T <sub>J</sub> = 25°C	Fig.4

#### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	R <sub>eJC</sub> Thermal Resistance from Junction to Case		°CM	Fig.6
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient		°C/W	
T <sub>sold</sub>	Soldering Temperature	260	°C	

## **Typical Performance**

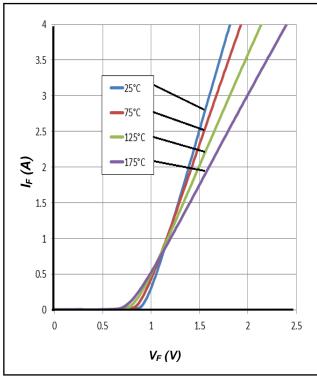


Figure 1. Forward Characteristics

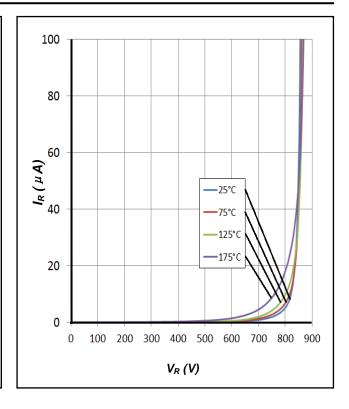
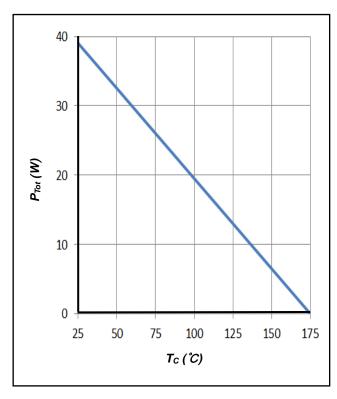


Figure 2. Reverse Characteristics

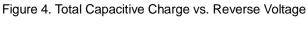
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## **Typical Performance**



(Se) 3 2 1 0 0 100 200 300 400 500 600 700 V<sub>R</sub> (V)

Figure 3. Power Derating



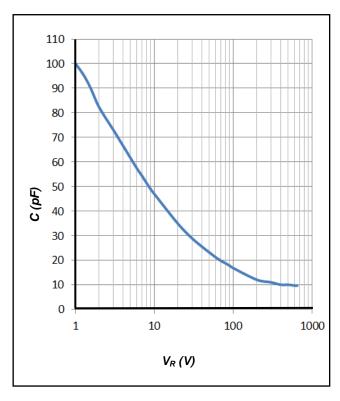


Figure 5. Total Capacitance vs. Reverse Voltage

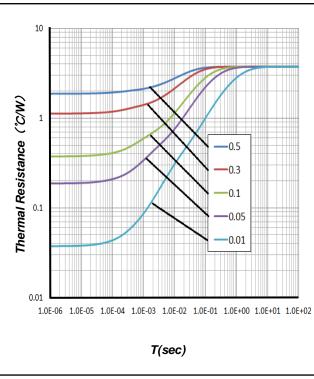
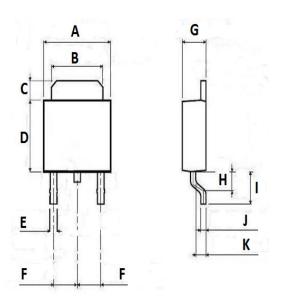


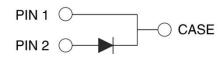
Figure 6. Transient Thermal Impedance



## **Package Dimensions**

Package TO-252

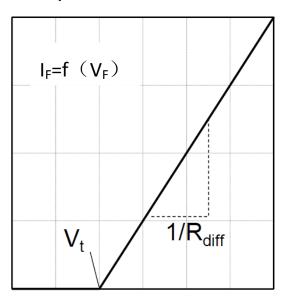




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
А	6.3	6.5	6.7
В	5.2	5.3	5.4
С	1.15	1.25	1.35
D	5.7	5.9	6.1
E	0.65	0.7	0.75
F	2.1	2.3	2.5
G	2.2	2.3	2.4
Н	1.45	1.5	1.55
I	2.9	3.0	3.1
J	0.45	0.5	0.55
K	0.9	1	1.1

## **Simplified Diode Model**

## **Equivalent IV Curve for Model**



### **Mathematical Equation**

$$V_F = V_t + I_F \times R_{diff}$$

$$V_t = -0.0011 \times T_j + 0.99 \text{ [V]}$$

$$R_{diff} = 3.67 \times 10^{-6} \times T_j^2 + 5.07 \times 10^{-4} \times T_j + 0.2 \text{ [}\Omega\text{]}$$

#### Note:

 $\label{eq:Tj} Tj = \mbox{Diode Junction Temperature In Degrees Celsius,} \\ \mbox{valid from } 25^{\circ}\mbox{C to } 175^{\circ}\mbox{C} \\ \mbox{I}_{\mbox{F=}} \mbox{Forward Current}$ 

Less than 4A



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